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30V, N-Channel NexFET™ Power MOSFETs

Check for Samples: CSD17306Q5A

FEATURES

- Optimized for 5V Gate Drive
- Ultralow Q_g and Q_{gd}
- Low Thermal Resistance
- Avalanche Rated
- Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 5-mm × 6-mm Plastic Package

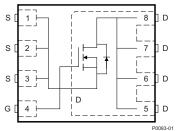
APPLICATIONS

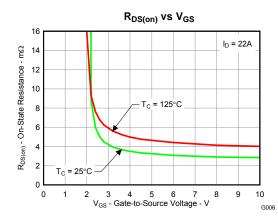
- Notebook Point of Load
- Point-of-Load Synchronous Buck in Networking, Telecom and Computing Systems

DESCRIPTION

The NexFET[™] power MOSFET has been designed to minimize losses in power conversion applications, and optimized for 5V gate drive applications.







PRODUCT SUMMARY

V _{DS}	Drain to Source Voltage 30					
Qg	Gate Charge Total (4.5V) 11.8					
Q _{gd}	Gate Charge Gate to Drain 2.4					
R _{DS(on)}		$V_{GS} = 3V$	4.2	mΩ		
	Drain to Source On Resistance	V _{GS} = 4.5V 3.3		mΩ		
		V _{GS} = 8V 2.9		mΩ		
V _{GS(th)}	Threshold Voltage	1.1	V			

ORDERING INFORMATION

Device	Package	Media	Qty	Ship
CSD17306Q5A	SON 5-mm × 6-mm Plastic Package	13-Inch Reel	2500	Tape and Reel

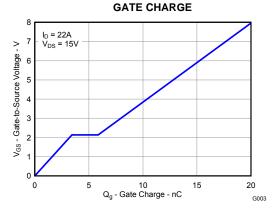
ABSOLUTE MAXIMUM RATINGS

T _A = 2	5°C unless otherwise stated	VALUE	UNIT
V_{DS}	Drain to Source Voltage	30	V
V_{GS}	Gate to Source Voltage	+10 /8	V
	Continuous Drain Current, T _C = 25°C	100	А
ID	Continuous Drain Current ⁽¹⁾	24	А
I _{DM}	Pulsed Drain Current, $T_A = 25^{\circ}C^{(2)}$	155	А
PD	Power Dissipation ⁽¹⁾	3.2	W
T _J , T _{STG}	Operating Junction and Storage Temperature Range	-55 to 150	°C
E _{AS}	Avalanche Energy, Single Pulse $I_D = 74A$, L = 0.1mH, $R_G = 25\Omega$	274	mJ

(1) Typical $R_{\theta JA} = 39^{\circ}C/W$ on a 1-inch² (6.45-cm²),

2-oz. (0.071-mm thick) Cu pad on a 0.06-inch (1.52-mm) thick FR4 PCB.

(2) Pulse duration $\leq 300 \mu s$, duty cycle $\leq 2\%$



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise stated)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Cl	naracteristics	·				
BV _{DSS}	Drain to Source Voltage	$V_{GS} = 0V, I_D = 250 \mu A$	30			V
I _{DSS}	Drain to Source Leakage Current	$V_{GS} = 0V, V_{DS} = 24V$			1	μA
I _{GSS}	Gate to Source Leakage Current	$V_{DS} = 0V, V_{GS} = +10 / -8V$			100	nA
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	0.9	1.1	1.6	V
		$V_{GS} = 3V, I_D = 22A$		4.2	5.4	mΩ
R _{DS(on)}	Drain to Source On Resistance	$V_{GS} = 4.5V, I_D = 22A$		3.3	4.2	mΩ
		V _{GS} = 8V, I _D = 22A		2.9	3.7	mΩ
9 _{fs}	Transconductance	V _{DS} = 15V, I _D = 22A		105		S
Dynamic	Characteristics	•				
C _{iss}	Input Capacitance			1670	2170	pF
C _{oss}	Output Capacitance	$V_{GS} = 0V, V_{DS} = 15V,$ f = 1MHz		890	1160	pF
C _{rss}	Reverse Transfer Capacitance			56	73	pF
R _G	Series Gate Resistance			1	2	Ω
Qg	Gate Charge Total (4.5V)			11.8	15.3	nC
Q _{gd}	Gate Charge Gate to Drain			2.4		nC
Q _{gs}	Gate Charge Gate to Source	$V_{DS} = 15V, I_D = 22A$		3.5		nC
Q _{g(th)}	Gate Charge at Vth			1.8		nC
Q _{oss}	Output Charge	V _{DS} = 13.4V, V _{GS} = 0V		23		nC
t _{d(on)}	Turn On Delay Time			7.8		ns
t _r	Rise Time	$V_{DS} = 15V, V_{GS} = 4.5V,$		13.1		ns
t _{d(off)}	Turn Off Delay Time	$I_{DS} = 22A, R_G = 2\Omega$		18.4		ns
t _f	Fall Time			6.4		ns
Diode Cl	haracteristics	· ·				
V _{SD}	Diode Forward Voltage	$I_{DS} = 22A, V_{GS} = 0V$		0.85	1	V
Q _{rr}	Reverse Recovery Charge			27		nC
t _{rr}	Reverse Recovery Time	V_{DD} = 14V, I _F = 25A, di/dt = 300A/µs		25		ns

THERMAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

	PARAMETER	MIN	TYP	MAX	UNIT
R_{\thetaJC}	Thermal Resistance Junction to Case ⁽¹⁾			0.9	°C/W
R_{\thetaJA}	Thermal Resistance Junction to Ambient ⁽¹⁾⁽²⁾			49	°C/W

 $R_{\theta JC}$ is determined with the device mounted on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch x 1.5-inch (3.81-cm x 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB. $R_{\theta JC}$ is specified by design, whereas $R_{\theta JA}$ is determined by the user's board design. Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu. (1)

(2)

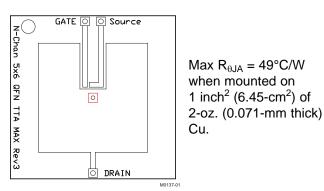


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GATE O Source

Max $R_{\theta,JA} = 120^{\circ}C/W$ when mounted on a minimum pad area of 2-oz. (0.071-mm thick) Cu.

TYPICAL MOSFET CHARACTERISTICS

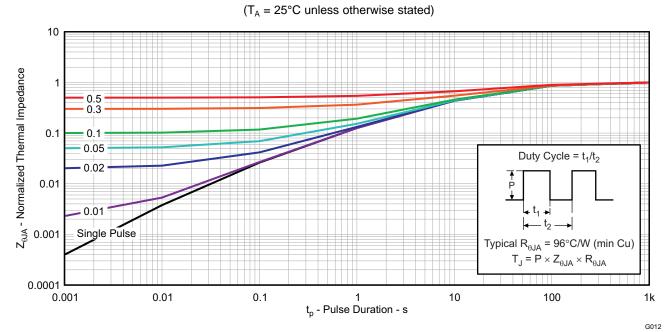


Figure 1. Transient Thermal Impedance

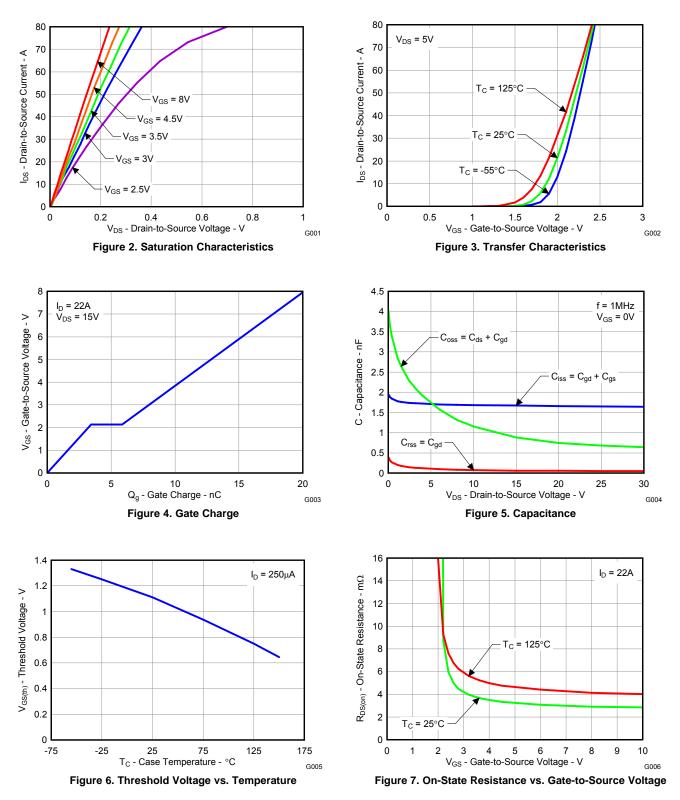
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TYPICAL MOSFET CHARACTERISTICS (continued)

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$



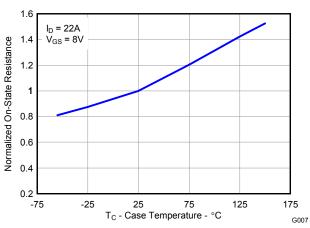


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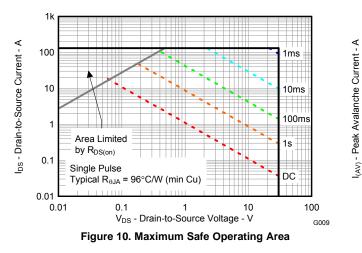
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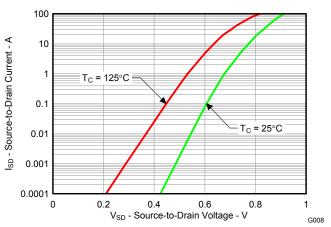
TYPICAL MOSFET CHARACTERISTICS (continued)

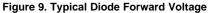
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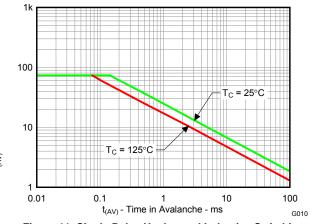




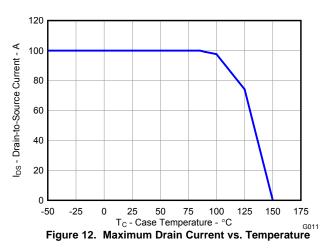










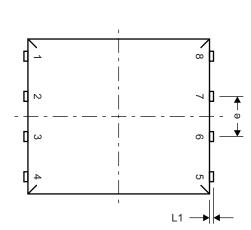


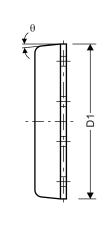
TEXAS INSTRUMENTS

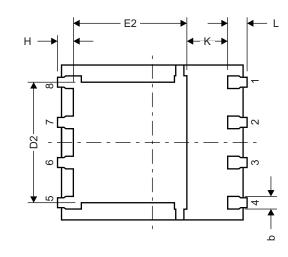
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MECHANICAL DATA

Q5A Package Dimensions



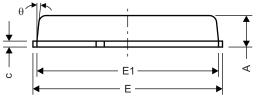




Top View

Side View

Bottom View



Front View

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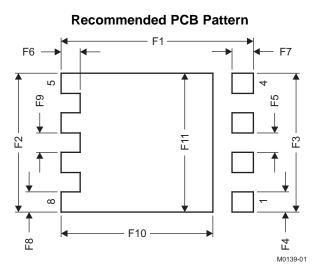
DIM		MILLIMETERS	
DIM	MIN	NOM	MAX
A	0.90	1.00	1.10
b	0.33	0.41	0.51
с	0.20	0.25	0.34
D1	4.80	4.90	5.00
D2	3.61	3.81	4.02
E	5.90	6.00	6.10
E1	5.70	5.75	5.80
E2	3.38	3.58	3.78
е	1.17	1.27	1.37
Н	0.41	0.56	0.71
К	1.10		
L	0.51	0.61	0.71
L1	0.06	0.13	0.20
θ	0°		12°



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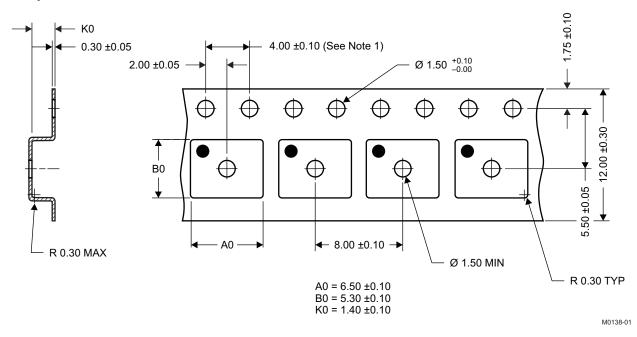
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DIM	MILLIM	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
F1	6.205	6.305	0.244	0.248
F2	4.46	4.56	0.176	0.18
F3	4.46	4.56	0.176	0.18
F4	0.65	0.7	0.026	0.028
F5	0.62	0.67	0.024	0.026
F6	0.63	0.68	0.025	0.027
F7	0.7	0.8	0.028	0.031
F8	0.65	0.7	0.026	0.028
F9	0.62	0.67	0.024	0.026
F10	4.9	5	0.193	0.197
F11	4.46	4.56	0.176	0.18

For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

Q5A Tape and Reel Information



Notes:

- 1. 10-sprocket hole-pitch cumulative tolerance ±0.2
- 2. Camber not to exceed 1mm in 100mm, noncumulative over 250mm
- 3. Material: black static-dissipative polystyrene
- 4. All dimensions are in mm (unless otherwise specified)
- 5. A0 and B0 measured on a plane 0.3mm above the bottom of the pocket

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REVISION HISTORY

C	hanges from Original (February 2010) to Revision A	Page
•	Updated the Q5A Package Dimensions table. DIM c MAX was 0.30, DIM D2 MAX was 3.96, DIM e MIN was blank MAX was blank, DIM H NOM was 0.51 MAX was 0.61	6
•	Deleted Note 6 from the Q5A Tape and Reel Information - "MSL1 260°C (IR and convection) PbF reflow compatible"	7
•	Deleted the Package Marking Information section	7

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6-Feb-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
CSD17306Q5A	ACTIVE	VSONP	DQJ	8	2500	Pb-Free (RoHS Exempt)	SN	Level-1-260C-UNLIM	-55 to 150	CSD17306	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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